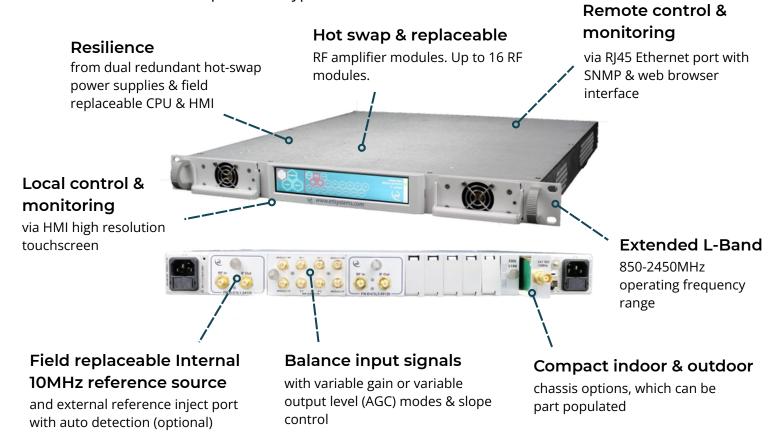


Alto Extended L-band Smart Amplifier Module

with low noise, high linearity, and variable gain

The extended L-Band low noise amplifier module is designed to work in the Genus 1U chassis series, operating over 850-2450 MHz. The module has low noise, high linearity, +45 to -4 dB variable gain with variable slope control. The chassis has the capacity for up to 16 amplifier modules, or can house a mixture of other hot-swap module types.



Chassis Specification				
Dimensions/Weight/Colour	1U high x 550mm deep x 19" wide / <10kg / RAL9003 - white (semi-matte)			
Capacity	ty 17 module slots. Note: Actual modules may require >1 slot. Refer to required module spec table.			
Temperature	Operating: 0°C to +45°C Storage: -20°C to +75°C			
Location/Humidity/Altitude	n/Humidity/Altitude Indoor use only / 20 to 90% non-condensing / 2,000m AMSL (Operational) 8,000m AMSL (Storage Above Mean Sea Level			
Local: HMI, capacitive touch screen ontrol & Monitoring Remote: Ethernet via RJ45, 10BaseT/100 BaseTx. ETL TCP/IP, SNMPv2/3, HTTPS & built-in w HMI and CPU field replaceable.				
MTTR	20 minutes (15 minutes to retrieve spare part and 5 mins to replace). Applies to LRUs only and assumed in-house stock.			
AC Input/Consumption	85-264Vac 50/60Hz / 275W max. consumption at steady state			
PSU Redundancy	dancy Dual redundant and alarmed. Diode OR. Hot swappable.			
Input & Output Ports	Dependant upon module fitted			





Smart Amplifier Module

Compact form factor allows multiple modules to be housed in the 1U GENUS chassis. Each module occupies 1 slot in the chassis.

High linearity ensures overall RF gain signal performance is optimised.

Low noise for prime signal quality.

		Smart Amplifier Module - RF Parar	neters	
Model Numbers		ALT-G1S-S3-102		
Frequency Range		850 - 2450 MHz		
Size		1 slot wide		
MTBF		>150,000 hrs. MTBF of each amp module. These are hot-swap		
RF Ports		50Ω SMA		
Gain		45 ± 2.0 dB max. -4 ± 2.0 dB min.		
Gain Flatness	850 - 2450 MHz	±0.6 dB	When set to 0dB slope. In manual gain control mode, not AGC.	
	Any 36MHz	±0.2 dB		
Gain Steps		0.25 ± 0.15 dB in manual gain mode		
Input Return Loss		18 dB typ.	14 dB min.	
Output Return Loss		18 dB typ.	14 dB min.	
Isolation		60dB Typ. 50dB Min.	With amplifiers set at the same gain level. Worst case isolation is between adjacent amps, isolation degrades dB to dB for different gain levels.	
Reverse Gain		< -60 dB typ.		
Noise Figure	Тур.	2 dB	At max. gain	
	Max.	3 dB	At max. gain	
1db GCP	Тур.	23 dBm	At max. gain	
	Min. 850- 2150MHz	20 dBm	At max. gain	
	Min. >2150MHz	19 dBm	At max. gain	
OIP3	Тур.	35 dBm	At max. gain	
	Min.	32 dBm	At max. gain	
OIP2	Тур.	45 dBm		
	Min.	41 dBm		
In band, signal independent spurii		<-85 dBm max.	Very low level spurii from CPU clock, switch mode PSU and other control electronics inside the chassis.	
Maximum Input Level		+20 dBm	For no damage. Non-operational.	



Interface, Monitoring & Alarms						
Control Method	Local and remote as provided by selected chassis					
LNB Power	None					
Environmental						
On a mating Tanana amata ma	-0°C to +50°C	Up to 8 modules in a chassis.				
Operating Temperature	-0°C to +45°C	Up to 16 modules in a chassis.				
Storage Temperature	-20°C to +75°C					
Location	Indoor use only, within parent GENUS chassis					
Humidity	20 to 90% non-condensing, relative humidity					
Altitude	10,000ft / 3,000m above mean sea level					
Physical Dimensions & Parameters						
Weight	<0.35kg typ.					

The performance quoted above is for a standalone amplifier. For in-chassis performance, see relevant spec. tables.

Note 1: The specification is subject to regular reviews and will be updated from time to time as part of our continuing product development and improved spec accuracy.

Note 2: Operation beyond the quoted limits stated above may cause instantaneous and permanent damage.